



4A HIGH VOLTAGE SCHOTTKY BARRIER RECTIFIER PowerDI®5

Features

- Lower Forward Voltage Drop than Ultrafast Rectifiers
- Very Low Leakage Current
- Soft Recovery Characteristics: Softness Factor $(t_b/t_a) \ge 1$ (see figure 8)
- Highly Stable Oxide Passivated Junction
- High Forward Surge Current Capability
- Lead Free Finish, RoHS Compliant (Note 1)
- "Green" Molding Compound (No Br, Sb)
- Qualified to AEC-Q101 Standards for High Reliability





Top View

Bottom View

Mechanical Data

- Case: PowerDI[®]5
- Case Material: Molded Plastic, "Green" Molding Compound.
 UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020D
- Terminals: Finish Matte Tin annealed over Copper leadframe. Solderable per MIL-STD-202, Method 208 @3
- Polarity: See Diagram
- Marking Information: See Page 3
- Ordering Information: See Page 3
- Weight: 0.095 grams (approximate)

RIGHT PIN O BOTTOMSIDE

Note: Pins Left & Right must be electrically connected at the printed circuit board.

Maximum Ratings @T_A = 25°C unless otherwise specified

Single phase, half wave, 60Hz, resistive or inductive load. For capacitance load, derate current by 20%.

Characteristic	Symbol	Value	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V _{RRM} V _{RWM} V _R	200	V
RMS Reverse Voltage	V _{R(RMS)}	141	V
Average Rectified Output Current (See also figure 5)	Io	4	Α
Non-Repetitive Peak Forward Surge Current 8.3ms Single half sine-wave Superimposed on Rated Load	I _{FSM}	100	Α

Thermal Characteristics

Characteristic	Symbol	Тур	Max	Unit
Thermal Resistance Junction to Soldering Point	$R_{ hetaJS}$	_	3.0	°C/W
Thermal Resistance Junction to Ambient Air (Note 2)	$R_{ hetaJA}$	80	_	°C/W
Thermal Resistance Junction to Ambient Air (Note 3)	$R_{ heta JA}$	65	_	°C/W
Thermal Resistance Junction to Ambient Air (Note 4)	$R_{ heta JA}$	45	_	°C/W
Operating and Storage Temperature Range	T _J , T _{STG}	-65 to +175		°C

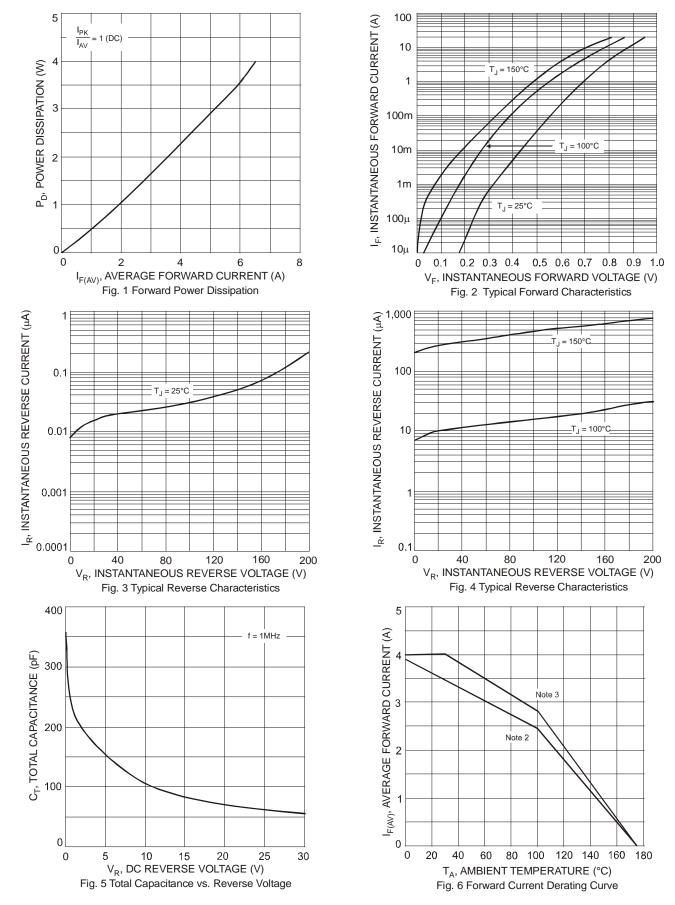
Electrical Characteristics @TA = 25°C unless otherwise specified

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
Reverse Breakdown Voltage (Note 5)	$V_{(BR)R}$	200	_	_	V	$I_R = 5\mu A$
		_	0.76	0.82		$I_F = 3A, T_S = 25^{\circ}C$
		_	_	0.59	\/	$I_F = 3A, T_S = 150^{\circ}C$
Forward Voltage	V-	_	0.785	0.84		$I_F = 4A, T_S = 25^{\circ}C$
	V _F	_	0.61	0.64		I _F = 4A, T _S = 150°C
		_	0.84	0.89		I _F = 8A, T _S = 25°C
		_	0.68	0.75		$I_F = 8A, T_S = 150^{\circ}C$
Poverse Leekoge Current (Note 5)	1-	_	0.2	1	μΑ	$T_S = 25^{\circ}C, V_R = 200V$
Reverse Leakage Current (Note 5)	IR	_	0.8	4	mA	$T_S = 150^{\circ}C, V_R = 200V$
Poverse Pecavery Time	4			25	ns	$I_F = 0.5A$, $I_R = 1.0A$
Reverse Recovery Time	t _{rr}	_	_		115	$I_{RR} = 0.25A$ (see Figure 8)

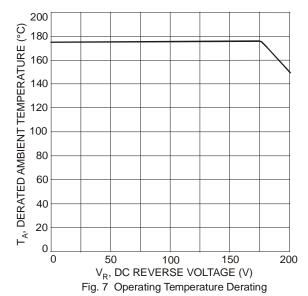
Notes:

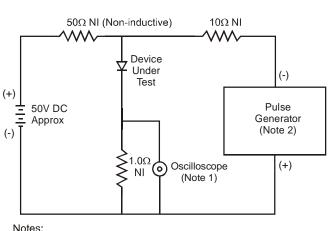
- 1. EU Directive 2002/95/EC (RoHS). All applicable RoHS exemptions applied, see EU Directive 2002/95/EC Annex Notes.
- 2. FR-4 PCB, 2 oz. Copper, minimum recommended pad layout per http://www.diodes.com/datasheets/ap02001.pdf.
- 3. Polymide PCB, 2 oz. Copper, minimum recommended pad layout per http://www.diodes.com/datasheets/ap02001.pdf. 4. Polymide PCB, 2 oz. Copper. Cathode pad dimensions 9.4mm x 7.2mm. Anode pad dimensions 2.7mm x 1.6mm.
- 5. Short duration test pulse used to minimize self-heating effect.

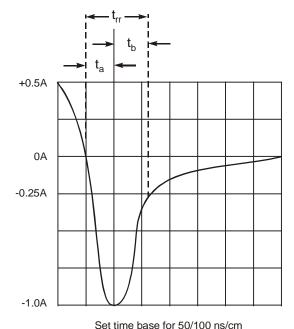












Notes:

- 1. Rise Time = 7.0ns max. Input Impedance = $1.0M\Omega$, 22pF.
- 2. Rise Time = 10ns max. Input Impedance = 50Ω .

Fig. 8 Reverse Recovery Time Characteristic and Test Circuit

Ordering Information (Note 6)

Part Number	Case	Packaging
PDS4200H-13	PowerDI [®] 5	5000/Tape & Reel

Notes: 6. For packaging details, go to our website at http://www.diodes.com/datasheets/ap02007.pdf.

Marking Information

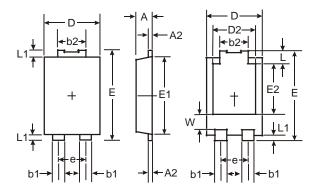


S4200H = Product type marking code → = Manufacturers' code marking YYWW = Date code marking YY = Last two digits of year ex: 06 for 2006 WW = Week code 01 to 52 K = Factory Designator

PowerDI is a registered trademark of Diodes Incorporated.

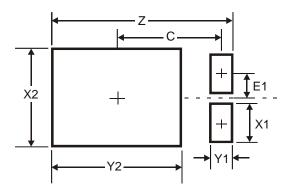


Package Outline Dimensions



PowerDI [®] 5			
Dim	Min	Max	
Α	1.05	1.15	
A2	0.33	0.43	
b1	0.80	0.99	
b2	1.70	1.88	
D	3.90	4.05	
D2	3.05 NOM		
Е	6.40	6.60	
е	1.84 NOM		
E1	5.30	5.45	
E2	E2 3.55 NOM		
L	0.75	0.95	
L1	0.50	0.65	
W	1.20	1.50	
All Dimensions in mm			

Suggested Pad Layout



Dimensions	Value (in mm)
Z	6.6
X1	1.4
X2	3.6
Y1	0.8
Y2	4.7
C	3.87
E1	0.9

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